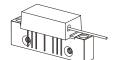


rfmd.com

RFOS501X

Package: SOT-115J

5MHz to 85MHz Si OPTICAL RECEIVER



Product Description

The RFOS501X is a hybrid high dynamic range optical receiver module. The module contains a single mode optical input suitable for wavelengths from 1290nm to 1600nm, a terminal to monitor the PIN diode current and an electrical output with an impedance of 75Ω .

VBIAS Optimum Technology Matching® Applied Optical OUTPUT GaAs HBT Input GaAs MESFET InGaP HBT Matching SiGe BiCMOS Network PP Amplifier Si BiCMOS SiGe HBT GaAs pHEMT Si CMOS Pin Detector Si BJT GaN HEMT **RF MEMS**

Features

- Superior Return Loss Performance
- Optimal Reliability
- Very Low EINC
- Standard CATV Outline
- Excellent Flatness
- Low Power Consumption
- SC/APC or FC/APC Optical Interface

Applications

■ 5 MHz to 85 MHz CATV Reverse Amplifier Systems

Parameter	Specification			Unit	Condition	
Falailletei	Min.	Тур.	Max.	OIIIL	Condition	
Overall					Bandwidth 5 MHz to 85 MHz; V_B =12V; T_{MB} =30 °C; Z_L =75 Ω	
Responsivity	2900	3100		V/W	λ=1310 nm, f=85 MHz	
Slope Straight Line ^[1]	0.0		1.0	dB	f=5MHz to 85MHz	
Flatness of O/E Response ^[2]		<0.3	0.5	dB	f=5MHz to 85MHz	
Optical Input Return Loss	45			dB		
Output Return Loss	17.0			dB	f=5MHz to 85MHz	
Equivalent Input Noise		1.8	2.2	pA/√HZ	f=10MHz to 85MHz	
Spectral Sensitivity	0.8			A/W	λ=(1310+-20)nm	
	0.90			A/W	λ=(1550+-20)nm	
Optical Wavelength	1290		1600	nm		
Total Current Consumption (DC)		100	105	mA		

^{1.} Slope is defined as the difference between the O/E response at the start frequency and the O/E response at the stop frequency. 2. Measured peak to valley.

RFOS501X



Absolute Maximum Ratings

Parameter	Rating	Unit
Frequency Range	5 to 85	MHz
Optical Input Power (continuous)	0	dBm
ESD Sensitivity (Human Body Model; R=1.5 k Ω , C=100 pF)	500	V
Storage Temperature	-40 to +85	°C
Operating Mounting Base Temperature	-20 to +85	°C



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

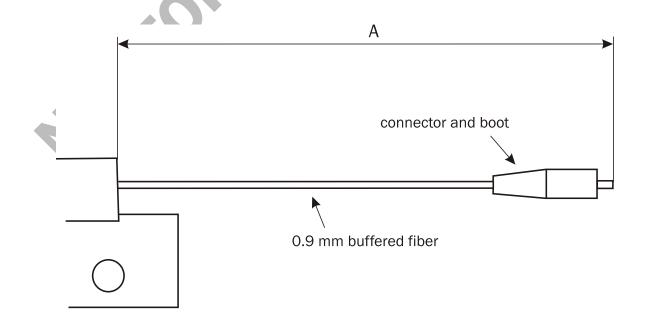
The information in this publication is believed to be accurate and reliable. However, no responsibility is assumed by RF Micro Devices, Inc. ("RFMD") for its use, nor for any infringement of patents, or other rights of third parties, resulting from its use. No license is granted by implication or otherwise under any patent or patent rights of RFMD. RFMD reserves the right to change component circuitry, recommended application circuitry and specifications at any time without prior notice.

Handling: Fiberglass optical coupling: maximum tensile strength=5N, minimum bending radius=35mm.

Parameter		Specification			Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition	
Distortion data						
Second order distortion ^[3]			-70.0	dBc	f _m =54.25MHz	
Third order distortion ^[4]			-70.0	dBc	f _m =55.25MHz	

Cable Lengths and Connector Types

Туре	Dimension A				Optical Connector
Type	Inches	Tolerance	mm	Tolerance	Туре
RF0S5012	33.4	-4 to +0.5	848	-102 to +13	FC/APC
RF0S5013	33.4	-4 to +0.5	848	-102 to +13	SC/APC

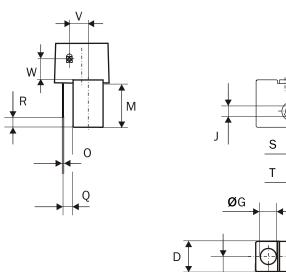


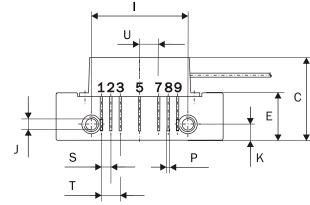
^{3.} The single second beat distortion (SSO) is measured using a two laser test. Each laser is modulated wiht a single tone at 13.3% OMI. The total optical power into the DUT is -10dBm (0.1mW) f1=20.25 MHz; f2=34.00 MHz; measurement at f1+f2.

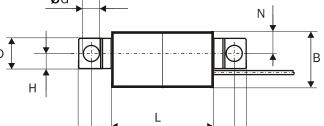
4. The single triple beat distortion (STB) is measured using a three laser test. Each laser is modulated with a single tone at 13.3% OMI. The total optical power into the DUT is -10dBm (0.1mW). f1=76.25 MHz; f2=64.25 MHz; f3=85.25 MHz; measurement at f1+f2-f3.











Α

All Dimensions in mm:

	nominal	min	max
Α	44,6 ^{± 0,2}	44,4	44,8
В	14,9 ^{± 0,2}	14,7	15,1
С	21,9 ^{± 0,5}	21,4	22,4
D	8 ^{± 0,15}	7,85	8,15
Е	12,6 ^{± 0,15}	12,45	12,75
F	38,1 ^{± 0,1}	38,0	38,2
G	4 +0,2/-0.05	3,95	4,2
Н	4 ^{± 0,2}	3,8	4,2
1	25,4 ^{± 0,2}	25,2	25,6
J	UNC 6-32	-	-
K	4,2 ^{± 0,2}	4,0	4,4
L	28,7 ^{± 0,2}	28,5	28,9
М	11,6 ^{± 0,5}	11,1	12,1
N	5,8 ^{± 0,4}	5,4	6,2
0	0,25 ^{± 0,02}	0,23	0,27
Р	0,45 ^{± 0,03}	0,42	0,48
Q	2,54 ^{± 0,3}	2,24	2,84
R	2,54 ^{± 0,5}	2,04	3,04
S	2,54 ^{± 0,25}	2,29	2,79
T	5,08 ^{± 0,25}	4,83	5,33
U	5,08 ^{± 0,25}	4,83	5,33
V	5,0 ^{± 0,2}	4,8	5,2
W	5,35		

Pinning:

1	PHOTODIODE CURRENT MONITOR
2	GND
3	GND
4	
5	+V _B
6	
7	GND
8	GND
9	OUTPUT

Notes:



0 5 10mm

RFOS501X



Typical Data: $V_B=12V$, $T_{MB}=30$ °C, $Z_L=75\Omega$

O/E slope (5MHz to 85MHz): 0.70dB O/E flatness (5MHz to 85MHz): 0.24dB

